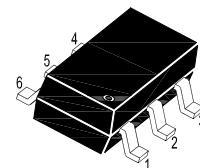
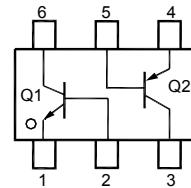


■ Dual Transistor (NPN+NPN)

■ Features

- Epitaxial planar die construction.
- Complementary Pair.
- Ultra-small surface mount package.
- One 2222A-Type NPN,
One 2907A-Type PNP.
- Ideal for low power amplification and switching



1. Collector 2. Base 3. Emitter
4. Emitter 5. Base 6. Collector

■ Simplified outline(SOT-363)

■ Absolute Maximum Ratings Ta = 25°C

- NPN 2222A

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	75	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current -Continuous	600	mA
P _D	Power Dissipation	200	mW
R _{θJA}	Thermal Resistance, Junction to Ambient	625	°C/W
T _{j,T_{stg}}	Junction and Storage Temperature	-55 to +150	°C

■ Absolute Maximum Ratings Ta = 25°C

- PNP 2907A

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current -Continuous	-600	mA
P _D	Power Dissipation	200	mW
R _{θJA}	Thermal Resistance, Junction to Ambient	625	°C/W
T _{j,T_{stg}}	Junction and Storage Temperature	-55 to +150	°C

■ Electrical Characteristics Ta = 25°C

- NPN 2222A

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =10µA,I _E =0	75	-	V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA,I _B =0	40	-	V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =10µA,I _C =0	6	-	V
Collector cut-off current	I _{CBO}	V _{CB} =60V,I _E =0 V _{CB} =60V,I _E =0,T _A =150°C	-	10 10	nA µA
Collector cut-off current	I _{CEX}	V _{CE} =60V,V _{EB(OFF)} =3.0V	-	10	nA
Emitter cut-off current	I _{EBO}	V _{EB} =3V I _C =0	-	10	nA
Base cut-off current	I _{BL}	V _{CE} =60V V _{EB(OFF)} =3.0V	-	20	nA
DC current gain	h _{FE}	V _{CE} =10V,I _C =100µA	35	-	
		V _{CE} =10V,I _C =1.00mA	50	-	
		V _{CE} =10V,I _C =10mA	75	-	
		V _{CE} =10V,I _C =150mA	100	300	
		V _{CE} =10V,I _C =500mA	40	-	
		V _{CE} =10V,I _C =10mA,T _A =-55°C	50	-	
		V _{CE} =1.0V,I _C =150mA,	35	-	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =150mA I _B =15mA I _C =500mA I _B =50mA	-	0.3 1.0	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =150mA I _B =15mA I _C =500mA I _B =50mA	0.6 -	1.2 2.0	V
Transition frequency	f _T	V _{CE} =20V,I _C =20mA,f=100MHz	300	-	MHz
Output Capacitance	C _{obo}	V _{CB} =10V,f=1.0MHz,I _E =0	-	8	pF
Input Capacitance	C _{ibo}	V _{EB} =0.5V,f=1.0MHz,I _C =0	-	25	pF
Noise Figure	NF	V _{CE} =10V,f=1.0kHz,I _C =0.1mA R _g =1.0KΩ,	-	4.0	dB
Delay Time	t _d	V _{CC} =30V,I _C =150mA, V _{BE(off)} =-0.5V,I _{B1} =15mA	-	10	ns
Rise Time	t _r		-	25	ns

■ Electrical Characteristics Ta = 25°C

- PNP 2907A

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-10µA I _E =0	-60	-	V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA I _B =0	-60	-	V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-10µA I _C =0	-5	-	V
Collector cut-off current	I _{CBO}	V _{CB} =-50V I _E =0 V _{CB} =-50V I _E =0 T _A =125°C	-	-10	nA µA
Collector cut-off current	I _{CEX}	V _{CE} =-30V V _{EB(OFF)} =-0.5V	-	-50	nA
Base cut-off current	I _{BL}	V _{CE} =-30V V _{EB(OFF)} =-0.5V	-	-50	nA
DC current gain	h _{FE}	V _{CE} =-10V I _C =-100µA V _{CE} =-10V I _C =-1mA V _{CE} =-10V I _C =-10mA V _{CE} =-10V I _C =-150mA V _{CE} =-10V I _C =-500mA	75 100 100 100 50	- - - 300 -	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-150mA I _B =-15mA I _C =-500mA I _B =-50mA	-	-0.4 -1.6	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =-150mA I _B =-15mA I _C =-500mA I _B =-50mA	-	-1.3 -2.6	V
Transition frequency	f _T	V _{CE} =-20V, I _C =-50mA, f=100MHz	200	-	MHz
Output Capacitance	C _{obo}	V _{CB} =-10V, f=1.0MHz, I _E =0	-	-8.0	pF
Input Capacitance	C _{ibo}	V _{EB} =-2.0V, f=1.0MHz, I _C =0	-	30	pF
Turn-on time	t _{on}	I _C =-150mA, V _{CC} =-30V, I _{B1} =-15mA	-	45	ns
Delay Time	t _d	V _{CC} =-30V, I _C =-150mA, I _{B1} =-15mA	-	10	ns
Rise Time	t _r		-	40	ns

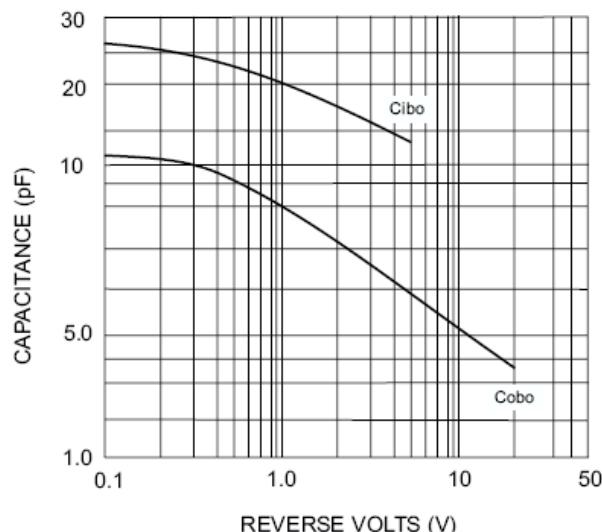


Fig. 1 (2222A) Capacitances (Typical)

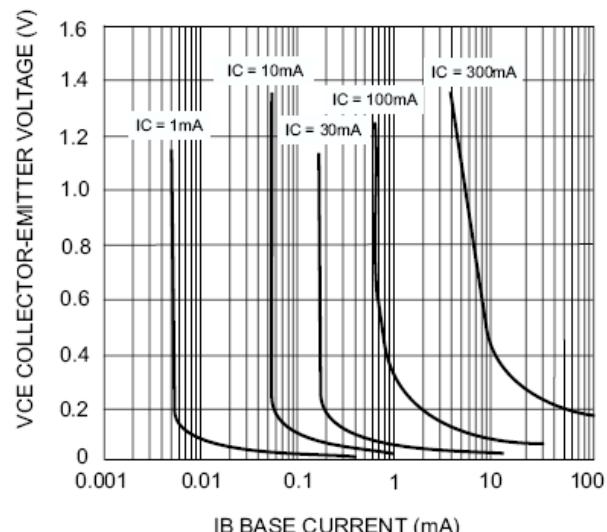


Fig. 4 (2907A) Typical Collector Saturation Region

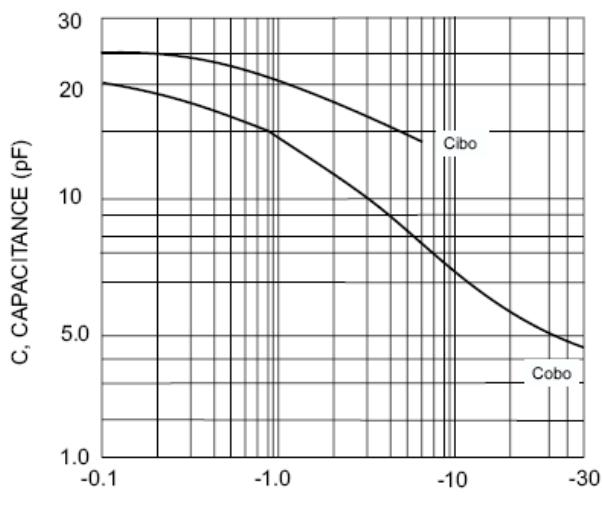


Fig. 3 (2907A) Capacitances (Typical)

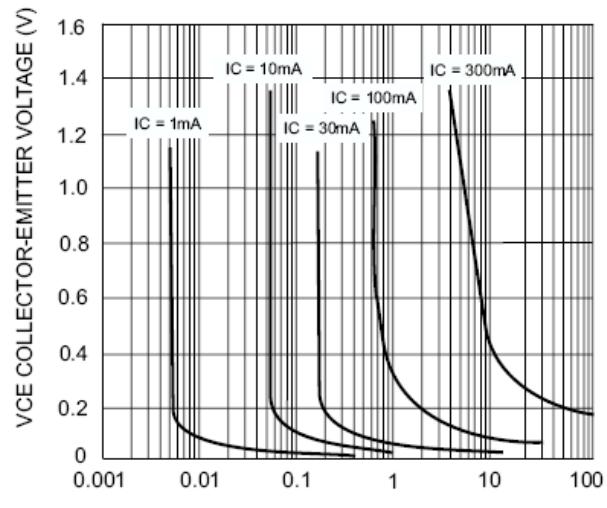
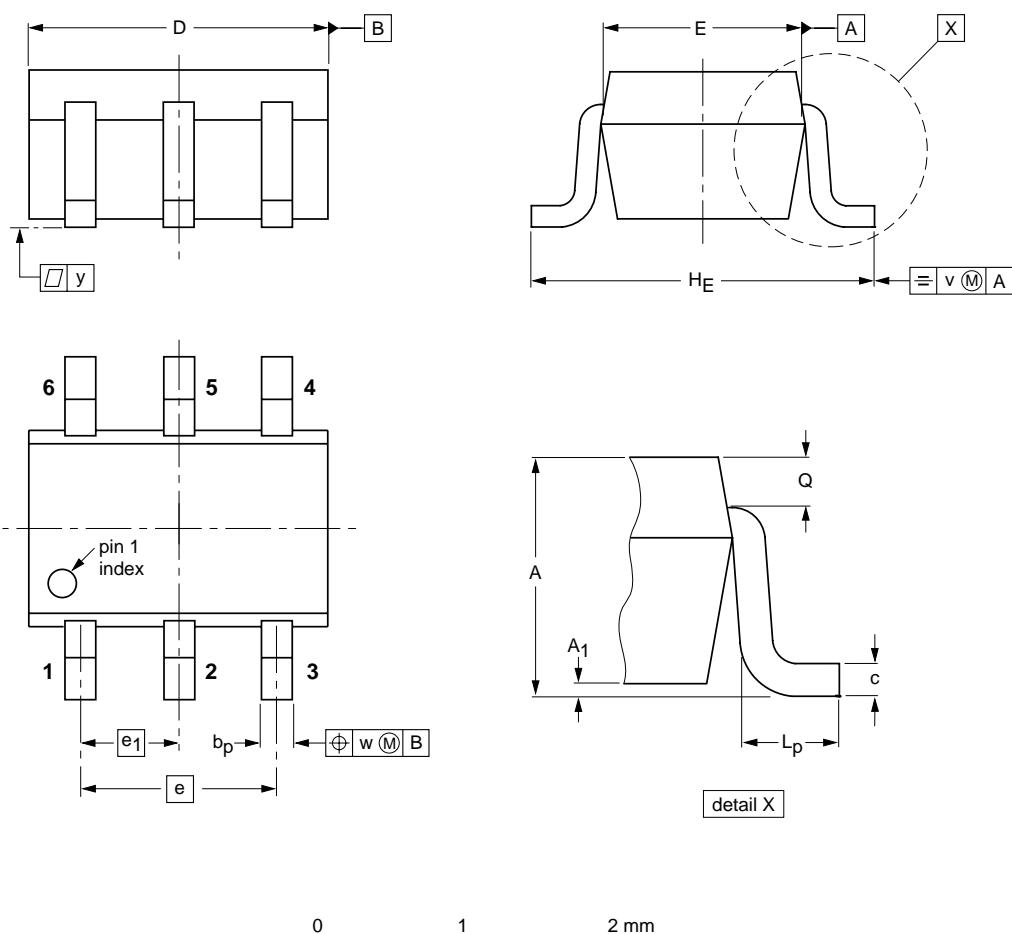


Fig. 4 (2907A) Typical Collector Saturation Region

■ SOT-363



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1